

UNITED STATES PATENT DOCUMENTS					
EXAMINER'S CITE NO.		PATENT NUMBER ISSUE DATE MM-DD-YYYY		FIRST NAMED INVENTOR	
		4810557	03/07/1989	Blender	
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FOREIGN PATENT DOCUMENTS								
EXAMINER'S INITIALS	CITE NO.	DOCUMENT NUMBER	COUNTRY OR REGION	DATE OF PUBLICATION MM-DD-YYYY	FIRST NAMED INVENTOR OR APPLICANT			
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		Suchtelen, et al. "Simulation of Anisotropic Wet-Chemical Etching Using a Physical Model," MESA		

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